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## M<sub>5</sub>X<sub>3</sub>-Type Rare Earth Silicides and Germanides and Their Ternary Phases with Carbon

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M<sub>5</sub>X<sub>3</sub>-type rare earth silicides crystallize in Cr<sub>5</sub>B<sub>3</sub>-type tetragonal (La–Nd) and Mn<sub>5</sub>Si<sub>3</sub>-type hexagonal structures (Sm–Lu except Eu). The corresponding germanides are all (except Eu and Yb) of the Mn<sub>5</sub>Si<sub>3</sub> type. Atomic parameters of the Mn<sub>5</sub>-Si<sub>3</sub>-type structure were determined, and the interatomic distances were calculated. M<sub>5</sub>X<sub>3</sub>C ternary phases were obtained for the Mn<sub>5</sub>Si<sub>3</sub>-type compounds with the same hexagonal structure but different lattice size. Geometrical arguments show that carbon occupies the octahedral holes of the hexagonal lattice.

### Introduction

The crystal structures of the rare earth silicides and germanides of general formula M<sub>5</sub>X<sub>3</sub> (X = Si, Ge) have been reported in a number of works. Except for the La–Nd silicide group,<sup>1,2</sup> which has the Cr<sub>5</sub>B<sub>3</sub>-type tetragonal structure, all of the other compounds crystallize in the Mn<sub>5</sub>Si<sub>3</sub>-type hexagonal form.<sup>3–13</sup>

A characteristic of this latter structure is that small metalloids (C, B, N, etc.) can be inserted into it without structural effect. Many transition metal silicides and germanides have been investigated for such phases. Recent studies on Mo<sub>5</sub>Si<sub>3</sub><sup>14</sup> have shown a possible stabilizing effect on the hexagonal structure of small amounts of carbon, nitrogen, or boron, these metalloids mainly occupying the octahedral holes formed by the hexagonal structure.

The aims of this work were the preparation of M<sub>5</sub>X<sub>3</sub>-type rare earth silicides and germanides, determination of the exact atomic parameters of the hexagonal lattice, and study of the effect of the addition of carbon on these compounds.

### Experimental Section

**Preparation.**—Rare earth metal lumps (99.9% purity) were filed to powder in a drybox filled with helium gas. The rare earth powder was thoroughly mixed with silicon or germanium (both of 99.9% purity) and pressed into disks, which were heated in an induction furnace at 1500–1600° until they melted. Heating of the samples was carried out in tantalum boats and was usually complete in 5 min. Before heating started, the reaction

site was repeatedly washed with argon in order to ensure a completely inert atmosphere during the reaction. The same procedure was used for preparing ternary phases with carbon.

Following preparation, the products were ground and analyzed by the X-ray diffraction method. The density of the compounds was determined by the pycnometric buoyancy method using water. X-Ray diffraction methods were used in the analysis of all of the reaction products.

**X-Ray.**—Thin layers of the powdered samples were spread out on microscopic slides coated with petrolatum and analyzed by the X-ray powder diffraction method, using a Philips diffractometer, the radiation being Ni-filtered Cu K $\alpha$  ( $\lambda$  1.5418 Å).

The unit cell was computed by a least-squares program<sup>15</sup> using an average of 20 reflections. Good agreement was obtained between observed and calculated  $\sin^2 \theta$  values. The maximum error in the lattice constants was  $\pm 0.01$  Å.

Values of the experimental structure factors were determined from carefully measured intensities. Intensity data were recorded on a strip chart while scanning the reflections at 0.5° (2 $\theta$ )/min. Each reflection was scanned twice, in increasing and decreasing angle directions. The areas of the peaks were measured with a planimeter. The structure factors were calculated by a computer program.<sup>16</sup>

### Results

Lattice parameters and density values obtained for the M<sub>5</sub>X<sub>3</sub>-type rare earth and yttrium silicides and germanides are given in Tables I–III. These results

TABLE I

LATTICE CONSTANTS OF Cr <sub>5</sub> B <sub>3</sub> -TYPE SILICIDES		
M <sub>5</sub> Si <sub>3</sub>	a, Å	c, Å
La <sub>5</sub> Si <sub>3</sub>	7.96	14.14
Ce <sub>5</sub> Si <sub>3</sub>	7.85	13.69
Pr <sub>5</sub> Si <sub>3</sub>	7.81	13.74
Nd <sub>5</sub> Si <sub>3</sub>	7.76	13.62

show that the La–Nd silicides crystallize in Cr<sub>5</sub>B<sub>3</sub>-type tetragonal unit cells, while the other silicides (except Eu) and the whole series of germanides (except Eu and Yb) have the Mn<sub>5</sub>Si<sub>3</sub>-type hexagonal structure.

In Figure 1, the values of the lattice constants were plotted against the atomic number of the rare earths. The decrease toward the higher atomic numbers corresponds well with the lanthanide contraction of the rare earth elements.

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TABLE II  
LATTICE CONSTANTS AND DENSITIES OF  
Mn<sub>5</sub>Si<sub>3</sub>-TYPE SILICIDES

M <sub>5</sub> Si <sub>3</sub>	a, Å	c, Å	d, g/cm <sup>3</sup>	
			Obsd	Calcd
Mn <sub>5</sub> Si <sub>3</sub>	8.58	6.48	6.65	6.72
Gd <sub>5</sub> Si <sub>3</sub>	8.52	6.39	7.06	7.20
Tb <sub>5</sub> Si <sub>3</sub>	8.43	6.30	7.43	7.44
Dy <sub>5</sub> Si <sub>3</sub>	8.39	6.28	7.58	7.78
Ho <sub>5</sub> Si <sub>3</sub>	8.34	6.25	8.05	8.00
Er <sub>5</sub> Si <sub>3</sub>	8.29	6.22	8.30	8.22
Tm <sub>5</sub> Si <sub>3</sub>	8.26	6.18	8.46	8.46
Yb <sub>5</sub> Si <sub>3</sub>	8.25	6.28	8.35	8.52
Lu <sub>5</sub> Si <sub>3</sub>	8.24	6.13	8.71	8.84
Y <sub>5</sub> Si <sub>3</sub>	8.42	6.32	4.50	4.52

TABLE III  
LATTICE CONSTANTS AND DENSITIES OF  
Mn<sub>5</sub>Si<sub>3</sub>-TYPE GERMANIDES

M <sub>5</sub> Ge <sub>3</sub>	a, Å	c, Å	d, g/cm <sup>3</sup>	
			Obsd	Calcd
La <sub>5</sub> Ge <sub>3</sub>	8.95	6.90	6.21	6.34
Ce <sub>5</sub> Ge <sub>3</sub>	8.84	6.72	6.67	6.70
Pr <sub>5</sub> Ge <sub>3</sub>	8.79	6.66	6.86	6.86
Nd <sub>5</sub> Ge <sub>3</sub>	8.74	6.60	7.03	7.14
Sm <sub>5</sub> Ge <sub>3</sub>	8.64	6.52	7.50	7.62
Gd <sub>5</sub> Ge <sub>3</sub>	8.57	6.43	7.96	8.16
Tb <sub>5</sub> Ge <sub>3</sub>	8.49	6.37	8.54	8.46
Dy <sub>5</sub> Ge <sub>3</sub>	8.44	6.33	8.67	8.76
Ho <sub>5</sub> Ge <sub>3</sub>	8.37	6.27	8.87	9.10
Er <sub>5</sub> Ge <sub>3</sub>	8.34	6.25	9.16	9.30
Tm <sub>5</sub> Ge <sub>3</sub>	8.30	6.22	9.31	9.50
Lu <sub>5</sub> Ge <sub>3</sub>	8.23	6.16	9.79	10.04
Y <sub>5</sub> Ge <sub>3</sub>	8.46	6.36	5.41	5.58

space group D<sub>6h</sub><sup>3</sup>-P6<sub>3</sub>/mcm. In order to determine the x<sub>I</sub> and x<sub>II</sub> values for the 6g<sub>I</sub> and 6g<sub>II</sub> positions of this space group, intensity measurements were carried out for several compounds. The atomic parameters and their standard deviations were determined by a least-squares refinement program. The best agreement between the observed and calculated values of the intensities in the cases of the silicides and germanides was found for x<sub>I</sub> = 0.24 ± 0.01 and x<sub>II</sub> = 0.60 ± 0.03. In Table IV observed and calculated values of the intensities are listed for Gd<sub>5</sub>Si<sub>3</sub>, Er<sub>5</sub>Si<sub>3</sub>, and Lu<sub>5</sub>Si<sub>3</sub> and for Ce<sub>5</sub>Ge<sub>3</sub>, Gd<sub>5</sub>Ge<sub>3</sub>, Er<sub>5</sub>Ge<sub>3</sub>, and Lu<sub>5</sub>Ge<sub>3</sub>.

Ternary phases of the M<sub>5</sub>X<sub>3</sub>-type compounds with varying amounts of carbon were prepared. The carbon added to the M<sub>5</sub>X<sub>3</sub> compounds was in the atomic ratios of 0.5, 1.0, 1.5, and 2.0. In the case of Cr<sub>5</sub>B<sub>3</sub>-type silicides, addition of carbon caused disappearance of the tetragonal structure and a complex pattern was obtained. An exception was Nd<sub>5</sub>Si<sub>3</sub>, in which, after the addition of carbon, the Mn<sub>5</sub>Si<sub>3</sub>-type hexagonal structure was formed. When carbon was added to the Mn<sub>5</sub>Si<sub>3</sub>-type silicides and germanides, the hexagonal structure remained until the composition of M<sub>5</sub>X<sub>3</sub>C. At higher carbon content, the hexagonal phase begins to disappear, and at M<sub>5</sub>X<sub>3</sub>C<sub>2</sub> a completely different but undetermined structure was obtained. In Table V lattice constants of the ternary silicides and germanides are given. It should be pointed out that in the cases of the germanides of La, Tb, Lu, and Y, additional phases

TABLE IV  
RELATIVE INTEGRATED INTENSITIES OF DIFFERENT Mn<sub>5</sub>Si<sub>3</sub>-TYPE RARE EARTH SILICIDES AND GERMANIDES

hkl	Gd <sub>5</sub> Si <sub>3</sub>		Er <sub>5</sub> Si <sub>3</sub>		Lu <sub>5</sub> Si <sub>3</sub>		Ce <sub>5</sub> Ge <sub>3</sub>		Gd <sub>5</sub> Ge <sub>3</sub>		Er <sub>5</sub> Ge <sub>3</sub>		Lu <sub>5</sub> Ge <sub>3</sub>	
	I <sub>obsd</sub>	I <sub>calcd</sub>	I <sub>obsd</sub>	I <sub>calcd</sub>	I <sub>obsd</sub>	I <sub>calcd</sub>	I <sub>obsd</sub>	I <sub>calcd</sub>	I <sub>obsd</sub>	I <sub>calcd</sub>	I <sub>obsd</sub>	I <sub>calcd</sub>	I <sub>obsd</sub>	I <sub>calcd</sub>
100	a	0.0	a	0.0	a	0.0	a	1.0	a	0.8	a	0.6	a	0.6
110	6.0	6.9	6.2	7.3	5.6	7.5	a	1.2	a	1.7	a	2.0	a	2.3
200	12.6	17.7	23.3	18.9	18.9	19.0	3.9	5.7	5.6	7.0	5.6	8.4	5.8	8.4
111	17.3	24.4	25.9	25.8	20.8	26.6	2.9	4.4	3.8	6.2	4.5	7.5	5.8	8.4
002	a	3.7	a	3.5	a	3.4	6.4	7.4	6.8	6.7	6.3	6.4	3.7	6.1
102	19.9	28.4	28.2	29.0	23.1	29.1	10.5	16.8	13.5	18.0	18.8	18.9	19.6	19.5
210	23.9	28.5	28.3	28.8	36.6	29.2	22.8	21.8	19.6	22.9	20.4	23.5	21.1	23.9
211	100.0	100.0	100.0	100.0	100.0	100.0	100.0	100.0	100.0	100.0	100.0	100.0	100.0	100.0
112	17.3	18.6	13.9	18.5	18.6	18.7	19.6	18.9	14.5	19.0	18.5	19.1	19.3	19.0
202	a	0.4	a	0.4	a	0.3	a	2.3	a	1.9	a	1.7	a	1.6
220	a	1.3	a	1.3	a	1.3	a	0.8	a	0.9	a	0.9	a	0.9
212	a	0.1	a	0.1	a	0.1	a	0.2	a	0.2	a	0.2	a	0.2
310	a	0.4	a	0.4	a	0.4	a	1.3	a	1.1	a	1.1	a	1.0
221	a	1.3	a	1.3	a	1.3	a	2.5	a	2.3	a	2.2	a	2.1
311	a	0.1	a	0.0	a	0.0	a	2.2	a	1.7	a	1.5	a	1.3
302	a	2.6	a	2.7	a	2.8	a	0.5	a	0.7	a	0.8	a	0.9
113	a	4.5	a	4.7	a	4.8	a	0.9	a	1.2	a	1.5	a	1.6
400	a	3.1	a	3.1	a	3.2	a	1.8	a	1.9	a	2.0	a	2.1
222	12.6	15.1	19.0	15.2	17.4	15.3	11.0	11.6	8.5	12.0	11.1	12.2	13.1	12.4
312	6.3	7.7	6.9	7.9	5.6	8.0	a	3.0	a	3.5	a	3.8	a	4.1
320					21.2	18.8	a	1.1						
	15.3	18.8	15.1						12.8	17.1	15.9	17.1	17.4	17.1
213			9.4	8.2	7.9	8.4	13.1	16.1						
321	11.3	8.2							4.7	6.3	6.1	6.4	4.3	6.5
004			30.4	23.0			18.1	12.2						
402	35.8	35.3			42.7	35.9			26.5	26.4	23.8	26.9	24.5	27.4
410			11.4	12.5			22.0	19.0						

<sup>a</sup> Not observed.

Density values of the different Mn<sub>5</sub>Si<sub>3</sub>-type silicides and germanides given in Tables II and III show good agreement with the calculations from crystal data, assuming the Mn<sub>5</sub>Si<sub>3</sub>-type structure with two formula units in the unit cell. The Mn<sub>5</sub>Si<sub>3</sub>-type unit cell has the

were obtained even at an M<sub>5</sub>Ge<sub>3</sub>C<sub>0.5</sub> composition. In the case of La<sub>5</sub>Ge<sub>3</sub>C<sub>1.5</sub>, a well-defined single phase was formed with a body-centered cubic lattice.<sup>17</sup>

TABLE V  
LATTICE CONSTANTS OF  
Ln<sub>5</sub>Si<sub>3</sub>C AND Ln<sub>5</sub>Ge<sub>3</sub>C COMPOUNDS

Compound	a, Å	c, Å	Compound	a, Å	c, Å
Nd <sub>5</sub> Si <sub>3</sub> C	8.66	6.60	Ce <sub>5</sub> Ge <sub>3</sub> C	8.84	6.72
Sm <sub>5</sub> Si <sub>3</sub> C	8.57	6.54	Pr <sub>5</sub> Ge <sub>3</sub> C	8.79	6.71
Gd <sub>5</sub> Si <sub>3</sub> C	8.52	6.46	Nd <sub>5</sub> Ge <sub>3</sub> C	8.74	6.68
Tb <sub>5</sub> Si <sub>3</sub> C	8.42	6.32	Sm <sub>5</sub> Ge <sub>3</sub> C	8.64	6.59
Dy <sub>5</sub> Si <sub>3</sub> C	8.38	6.36	Gd <sub>5</sub> Ge <sub>3</sub> C	8.57	6.52
Ho <sub>5</sub> Si <sub>3</sub> C	8.33	6.32	Tb <sub>5</sub> Ge <sub>3</sub> C	8.49	6.41
Er <sub>5</sub> Si <sub>3</sub> C	8.29	6.30	Dy <sub>5</sub> Ge <sub>3</sub> C	8.45	6.42
Tm <sub>5</sub> Si <sub>3</sub> C	8.26	6.26	Ho <sub>5</sub> Ge <sub>3</sub> C	8.37	6.38
Yb <sub>5</sub> Si <sub>3</sub> C	8.25	6.28	Er <sub>5</sub> Ge <sub>3</sub> C	8.34	6.37
Lu <sub>5</sub> Si <sub>3</sub> C	8.25	6.15	Tm <sub>5</sub> Ge <sub>3</sub> C	8.30	6.32
Y <sub>5</sub> Si <sub>3</sub> C	8.40	6.40	Lu <sub>5</sub> Ge <sub>3</sub> C	8.23	6.26
			Y <sub>5</sub> Ge <sub>3</sub> C	8.45	6.45

### Discussion

Two types of crystal structure were obtained with the M<sub>5</sub>X<sub>3</sub>-type compounds: the Cr<sub>5</sub>B<sub>3</sub>-type tetragonal and the Mn<sub>5</sub>Si<sub>3</sub>-type hexagonal structures. Of these two structures, the Mn<sub>5</sub>Si<sub>3</sub> type is the more densely packed. In this structure, layers containing both metals and nonmetals are present, while in the Cr<sub>5</sub>B<sub>3</sub> structure the nonmetals are located between the metallic layers. The formation of one of these structures will therefore depend on the ratio  $R_M/R_X$ . When this ratio is larger than 1.37, the Cr<sub>5</sub>B<sub>3</sub> structure forms, while at lower values (in our case beginning from Sm<sub>5</sub>Si<sub>3</sub>) the more

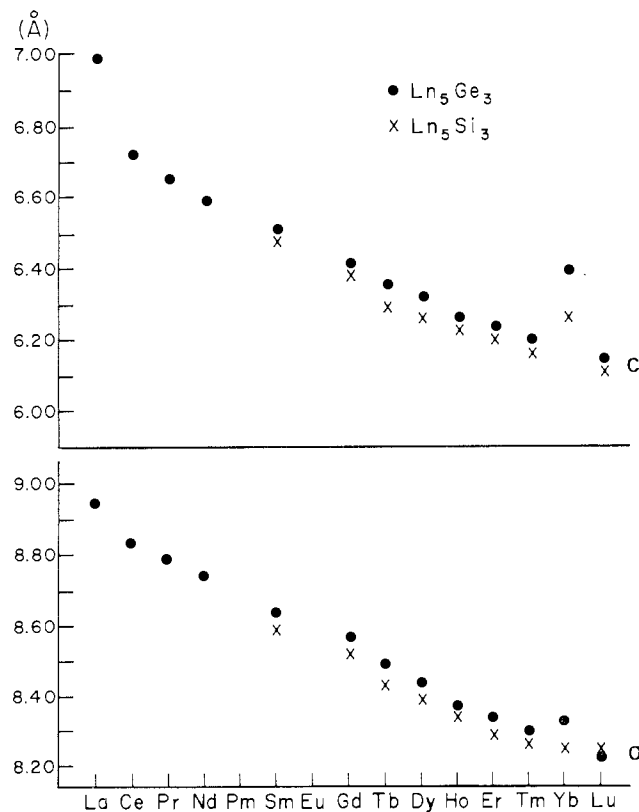


Figure 1.—Variation of the lattice constants  $a$  and  $c$  with the atomic number, for Ln<sub>5</sub>Si<sub>3</sub> and Ln<sub>5</sub>Ge<sub>3</sub> compounds.

TABLE VI  
INTERATOMIC DISTANCES IN THE Mn<sub>5</sub>Si<sub>3</sub>-TYPE SILICIDES AND GERMANIDES (Å)<sup>a</sup>

Compound	M(4d)			M(6g)					X		M(6g)- M(6g)
	6X	2M(4d)	6M(6g)	2X	1X	2X	2M(6g)	4M(6g)	2X	2X	
Sm <sub>5</sub> Si <sub>3</sub>	3.08	3.24	3.71	2.99	3.1	3.5	3.6	3.84	3.7	4.5	5.2
Gd <sub>5</sub> Si <sub>3</sub>	3.05	3.19	3.67	2.97	3.1	3.5	3.5	3.79	3.6	4.5	5.2
Tb <sub>5</sub> Si <sub>3</sub>	3.02	3.15	3.63	2.94	3.0	3.4	3.5	3.75	3.6	4.5	5.1
Dy <sub>5</sub> Si <sub>3</sub>	3.01	3.14	3.62	2.92	3.0	3.4	3.5	3.73	3.6	4.4	5.1
Ho <sub>5</sub> Si <sub>3</sub>	2.99	3.12	3.60	2.91	3.0	3.4	3.5	3.71	3.6	4.4	5.1
Er <sub>5</sub> Si <sub>3</sub>	2.97	3.11	3.58	2.89	3.0	3.4	3.5	3.69	3.6	4.4	5.1
Tm <sub>5</sub> Si <sub>3</sub>	2.96	3.09	3.56	2.88	3.0	3.4	3.4	3.67	3.5	4.4	5.0
Yb <sub>5</sub> Si <sub>3</sub>	2.97	3.14	3.57	2.87	3.0	3.4	3.4	3.71	3.6	4.4	5.0
Lu <sub>5</sub> Si <sub>3</sub>	2.95	3.06	3.55	2.87	3.0	3.4	3.4	3.65	3.5	4.4	5.0
Y <sub>5</sub> Si <sub>3</sub>	3.02	3.16	3.63	2.94	3.0	3.4	3.5	3.75	3.6	4.5	5.1
La <sub>5</sub> Ge <sub>3</sub>	3.23	3.45	3.88	3.12	3.2	3.7	3.7	4.06	3.9	4.7	5.5
Ce <sub>5</sub> Ge <sub>3</sub>	3.18	3.36	3.82	3.08	3.2	3.6	3.7	3.97	3.8	4.7	5.4
Pr <sub>5</sub> Ge <sub>3</sub>	3.16	3.33	3.80	3.06	3.2	3.6	3.7	3.94	3.8	4.7	5.4
Nd <sub>5</sub> Ge <sub>3</sub>	3.14	3.30	3.77	4.04	3.2	3.6	3.6	3.91	3.7	4.6	5.3
Sm <sub>5</sub> Ge <sub>3</sub>	3.10	3.26	3.73	3.01	3.1	3.5	3.6	3.86	3.7	4.6	5.3
Gd <sub>5</sub> Ge <sub>3</sub>	3.07	3.22	3.70	2.99	3.1	3.5	3.6	3.82	3.6	4.5	5.2
Tb <sub>5</sub> Ge <sub>3</sub>	3.05	3.19	3.66	2.96	3.1	3.5	3.5	3.78	3.6	4.5	5.2
Dy <sub>5</sub> Ge <sub>3</sub>	3.03	3.16	3.64	2.94	3.0	3.4	3.5	3.76	3.6	4.5	5.1
Ho <sub>5</sub> Ge <sub>3</sub>	3.00	3.13	3.61	2.92	3.0	3.4	3.5	3.72	3.6	4.4	5.1
Er <sub>5</sub> Ge <sub>3</sub>	2.99	3.12	3.60	2.91	3.0	3.4	3.5	3.71	3.5	4.4	5.1
Tm <sub>5</sub> Ge <sub>3</sub>	2.97	3.11	3.58	2.89	3.0	3.4	3.5	3.69	3.5	4.4	5.1
Lu <sub>5</sub> Ge <sub>3</sub>	2.95	3.08	3.55	2.87	3.0	3.4	3.4	3.66	3.5	4.4	5.0
Y <sub>5</sub> Ge <sub>3</sub>	3.03	3.18	3.65	2.95	3.1	3.5	3.5	3.77	3.6	4.5	5.2

<sup>a</sup> Estimated mean deviations (Å): M(4d)-6X, ±0.05; M(4d)-2M(4d), ±0.01; M(4d)-6M(6g), ±0.05; M(6g)-2X, ±0.05; M(6g)-1X, ±0.2; M(6g)-2X, ±0.1; M(6g)-2M(6g), ±0.15; M(6g)-4M(6g), ±0.05; X-2X, ±0.25; X-2X, ±0.15; M(6g)-M(6g), ±0.14.

densely packed Mn<sub>5</sub>Si<sub>3</sub> structure is preferred. The critical importance of the value of  $R_M/R_X$  in the formation of one of the above structures was also proved in the case of the transition and alkaline earth silicides and germanides.<sup>1,18</sup>

Attempts to prepare M<sub>5</sub>X<sub>3</sub>-type europium compounds were unsuccessful, and only Yb<sub>5</sub>Si<sub>3</sub> was obtained in the case of ytterbium. A possible reason for these findings might be the divalency of Eu and Yb in the metallic

state, with metallic radii much too large for the formation of one of the above structures.

In Table VI, bond lengths between the atoms in the  $Mn_5Si_3$ -type lattices are listed. The shortest distance between the metals is in the 4d position. Taking half these distances, one gets values equal to the covalent radii of these metals. On the other hand, the bond length between the metals in the 6g position equals the length known in the metallic state. It can therefore be concluded that the metal-metal bond in the lattice is of two different types, covalent in the  $c$  direction (4d), and of a metallic character in the layers normal to the  $c$  axis (6g).

Carbon atoms occupy the 0, 0, 0 and 0, 0,  $1/2$  positions in the lattice and so are located in octahedral holes formed by the 6g metals. Table VII lists the diameters of the octahedral holes in the  $Mn_5Si_3$ -type lattice for the various binary compounds, as well as for the compounds containing carbon. The third column contains the effective radii of carbon in the ternary phases. The diameter of the octahedral holes ( $D$ ) was calculated by the expression

$$D = r_{oct} - r_{M_{6g}}$$

where  $r_{oct}$  is the diagonal length between two metals in neighboring layers ( $\sqrt{(1 - 2x_M)^2c^2 + (0.5x)^2a^2}$ ), and  $r_{M_{6g}}$  is the metal-metal distance in the 6g position ( $1.732ax_M$ ).

From the values shown in Table VII it can be seen that the diameter of the octahedral holes decreases toward the heavier rare earth elements and that the effective radii of carbon (actually half the diameter of the octahedral hole) in these compounds have values falling between the values of the covalent radius ( $0.77 \text{ \AA}^{19}$ ) and atomic radius ( $0.914 \text{ \AA}^{20}$ ) of carbon.

These facts explain the increase of cell constant  $c$  in

the ternary phases toward the heavier elements, this increase being necessary for the existence of octahedral holes with enough space for the location of the carbon atoms. Because of their size, the octahedral holes can accommodate one carbon atom only, in good agreement with our experimental results. According to the values of the estimated effective radii of the carbon, the bonds formed between the metals and carbon are essentially atomic with a slight covalent character.

TABLE VII  
DIAMETERS OF THE OCTAHEDRAL HOLES ( $D$ ) AND  
RADII OF CARBON ( $R_C$ ) IN VARIOUS  
 $Mn_5Si_3$ -TYPE LATTICES

M	$M_5Si_3$	$M_4Si_3C$		$M_6Ge_3$	$M_5Ge_3C$	
	$D, \text{ \AA}$	$D, \text{ \AA}$	$R_C$	$D, \text{ \AA}$	$D, \text{ \AA}$	$R_C$
Ce	...	...	...	1.74	1.74	0.87
Pr	...	...	...	1.73	1.74	0.87
Nd	...	1.70	0.85	1.71	1.73	0.865
Sm	1.65	1.69	0.845	1.68	1.71	0.855
Gd	1.65	1.67	0.835	1.66	1.67	0.835
Tb	1.64	1.63	0.815	1.64	1.66	0.83
Dy	1.62	1.65	0.825	1.63	1.66	0.83
Ho	1.61	1.64	0.82	1.62	1.65	0.825
Er	1.60	1.63	0.185	1.61	1.65	0.825
Tm	1.60	1.62	0.81	1.60	1.64	0.82
Yb	1.62	1.62	0.81	...	...	...
Lu	1.57	1.58	0.79	1.59	1.62	0.81
Y	1.63	1.66	0.83	1.64	1.67	0.835

Stabilization of the hexagonal structure was obtained in the case of  $Nd_5Si_3$  by filling the octahedral holes with carbon. In view of the ratio  $R_M/R_{Si}$ ,  $Nd_5Si_3$  would not crystallize in the  $Mn_5Si_3$ -type structure, but the addition of carbon in the octahedral holes and formation of  $Nd_5C$  bonds caused an energy gain, thus stabilizing the hexagonal phase.

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## The Chloramination of Some Ditertiary Phosphines and Arsines

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The reactions of various phenyl-substituted ditertiary phosphines and arsines with chloramine have been shown to result in the formation of double-chloramination products in the presence of ammonia. In some cases, monochloramination products could be isolated using ammonia-free chloramine. The new compounds obtained have been characterized by their elemental analyses and infrared and proton magnetic resonance spectra.

### Introduction

It has been well established that chloramine reacts with tertiary phosphines or arsines to form amino-phosphonium or aminoarsonium chlorides.<sup>1-4</sup> Apart

from the simple tertiary phosphines, reactions of chloramine with systems containing more than one phosphorus atom and more than one basic site, *e.g.*, bis(diphenylphosphino)amines<sup>5</sup> and bis(diphenylphosphino)hydrazines,<sup>6,7</sup> have been studied and it has been shown that chloramination always occurs on the phos-

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